

APPLICANT'S ART CITATION <i>O I P E J O U S e several sheets if necessary</i>		Application 09/955,366		OFGS File No. P/126-209									
		Applicant YAMADA, T.											
		Filing Date 9/18/01		Group Art Unit --									
U.S. PATENT DOCUMENTS													
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MJH	9-	2	4	7	6	7	3	9/1997	JAPAN			Abst	
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)													
Examiner	<i>Martina Hany</i>			Date Considered	11/16/04								
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PTO/SB/08a/b (08-03)
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Substitute for form 1449A/B/PTO				Complete if Known		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>				Application Number	09/955,366-Conf. #8343	
Sheet	1	of	1	Filing Date	September 18, 2000	
				First Named Inventor	Toru Yamada	
				Art Unit	2121	
				Examiner Name	Not Yet Assigned	
				Attorney Docket Number		G0126.0209/P209

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (<i>if known</i>)			

FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Country Code ³ -Number ⁴ -Kind Code ⁵ (<i>if known</i>)			
MJH	BA	JP-9-055926	02-25-1997	Nippon Telegr & Teleph Corp	
MJH	BB	JP-8-317384	11-29-1996	Hitachi Ltd	
MJH	BC	JP-2000-217111	08-04-2000	Matsushita Electric Ind Co Ltd	

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		T ²			
MJH	CA	Japanese Office Action issued April 6, 2004 (w/ English translation of relevant portions)			

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